NSN 5961-01-243-5499

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-243-5499 **Inclosure Material:** Glass **Overall Length:** 2.250 inches **Terminal Length:** 0.345 inches **Overall Diameter:** 0.500 inches **Function For Which Designed:** Transient suppressor **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 170.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 47.00 amperes source cutoff current universal **Power Rating Per Characteristic:** 15.0 kilowatts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 80.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0